

6RI 75G-120/160

POWER DIODE MODULE

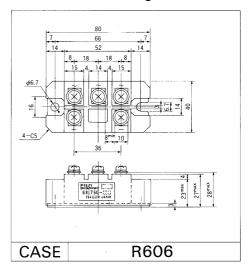
Features

- All the terminals and the mounting plate are electrically isolated. These modules can be installed in the same cooling fin as other modules, thus saving installation space – a cost-effective feature.
- The diode chips are coated with a glass of zinc oxide, making them highly resistant to temperature and humidity variation.
- 6 diode chips are connected to the 3-phase bridge rectifying circuit inside the module-a cost-effective feature.

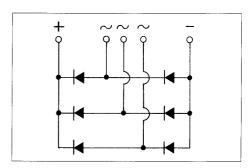
Applications

- Inverters for AC motors
- Power supply units for DC motors
- DC power supply units for battery chargers
- General purpose DC power supply units

■ Outline Drawings



■ Inner Circuit Schematic



■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings

Items	Symbols	Conditions	6R175G		Units
			-120	-160	Units
Repetitive peak reverse voltage	V_{RRM}		1200	1600	V
Non-repetitive peak reverse voltage	V _{RSM}		1320	1760	V
Average output current	l _o	50/60 Hz Sinewave,T _C = 93°C	75		А
Surge current	I _{FSM}	Rated load conditions	1000		А
2 _t	l ² _t	Rated load conditions	4000		A ² s
Junction temperature	T _j		-40~+150		°C
Storage temperature	T _{stg}		-40~+125		°C
Tightening torque		Mounting screw: M5	25±5		kg.cm
Vibration resistance			5		G
Dielectric strength		Between terminals and base	2500 VAC 1 min		
Net. Weight		,	230		g

Electrical Characteristics

Items	Symbols	Conditions	Min	Тур	Max	Units
Forward voltage	V _{FM}	T _j =25°C, I _{FM} =75 A		,	1.30	V
Reverse current	I _{RRM}	$T_i=150$ °C, $V_R=V_{RRM}$			15	mA

• Thermal Characteristics

ltems	Symbols	Conditions	Min	Тур	Max	Units
Thermal resistance (Junction to case)	R _{th(j-c)}	50/60 Hz Sinewave, Thermal resistance for total loss			0.30	°C/W
Thermal resistance	R _{th(c-f)}	With thermal compound			0.06	°C/W